

400V 30A Ignition IGBT

BV _{CES}	400±30V
I _C	30A
V _{CE(sat) (Typ.)}	1.6V
E _{AS}	300mJ

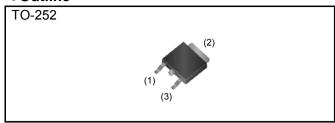
Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Self-Clamped Inductive Switching Energy
- 3) Built in Gate-Emitter Protection Diode
- 4) Built in Gate-Emitter Resistance
- 5) Qualified to AEC-Q101
- 6) Pb free Lead Plating; RoHS Compliant

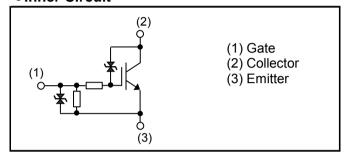
Applications

Ignition Coil Driver Circuits
Solenoid Driver Circuits

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Taping
	Reel Size (mm)	330
Typo	Tape Width (mm)	16
Туре	Basic Ordering Unit (pcs)	2,500
	Packing Code	TL
	Marking	RGPR30BM40

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	430	V
Emitter-Collector Voltage (V _{GE} = 0\	/)	V _{EC}	25	V
Gate - Emitter Voltage		V_{GES}	±10	V
Collector Current	I _C	30	А	
A	T _j = 25°C	E _{AS}	300	mJ
Avalanche Energy (Single Pulse)	T _j = 150°C	E _{AS} ^{*2}	180	mJ
Power Dissipation	P _D	125	W	
Operating Junction Temperature	T _j	-40 to +175	°C	
Storage Temperature	T _{stg}	-55 to +175	°C	

●Thermal Resistance

Parameter	Symbol	Values			Unit
- Farametei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	1.20	°C/W

ullet Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
- Farameter	Symbol Conditions		Min.	Тур.	Max.	Offic
		$I_C = 2mA$, $V_{GE} = 0V$				
Collector - Emitter Breakdown Voltage	BV _{CES}	T _j = 25°C	370	400	430	V
		$T_j = -40 \text{ to } 175^{\circ}\text{C}^{*2}$	365	-	435	V
Emitter - Collector Breakdown Voltage	BV _{EC}	$I_{\rm C} = -10 {\rm mA}, \ V_{\rm GE} = 0 {\rm V}$	25	35	-	V
Gate - Emitter Breakdown Voltage	BV_GES	$I_G = \pm 5$ mA, $V_{CE} = 0$ V	±12	1	±17	V
		V _{CE} = 250V, V _{GE} = 0V				
Collector Cut - off Current	I _{CES}	T _j = 25°C	-	-	7	μA
		$T_j = 150^{\circ}C^{*2}$	-	-	100	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 10V, V_{CE} = 0V$	±0.4	±0.6	±1.2	mA
		$V_{CE} = 5V$, $I_C = 12mA$				
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	T _j = 25°C	1.3	1.7	2.1	V
		$T_j = 150^{\circ}C^{*2}$	-	1.3	-	V
		I _C = 12A, V _{GE} = 5V				
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	T _j = 25°C	-	1.60	2.00	V
		T _j = 150°C	-	1.80	-	V
		$I_C = 5A, V_{GE} = 4.5V$				
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	T _j = 25°C	-	1.17	1.50	V
		T _j = 150°C	-	1.19	-	V

●Electrical Characteristics (at T_i = 25°C unless otherwise specified)

Darameter	Symbol	Conditions	Values			Linit
Parameter Symbo		Conditions	Min.	Тур.	Max.	Unit
		I _C = 12A, V _{GE} = 4V				
Collector - Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	T _j = 25°C	-	1.70	2.10	V
		T _j = 150°C	-	1.90	-	V
Input Capacitance	C _{ies}	V _{CE} = 10V	ı	1330	ı	
Output Capacitance	C _{oes}	V _{GE} = 0V	ı	220	ı	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	ı	71	ı	
Total Gate Charge	Q_g	$V_{CE} = 12V, I_{C} = 10A,$ $V_{GE} = 5V$	-	22	-	nC
Turn - on Delay Time*1,*2	t _{d(on)}		0.11	0.19	0.50	
Rise Time*1,*2	t _r	$I_C = 8A, V_{CC} = 300V,$	0.10	0.18	0.50	μs
Turn - off Delay Time*1,*2	$t_{d(off)}$	V_{GE} = 5V, R_{G} = 100 Ω , L=5mH, T_{J} =25 $^{\circ}$ C	0.9	1.4	4.0	
Fall Time*1,*2	t _f		0.8	1.8	5.5	
Turn - on Delay Time ^{*1}	$t_{d(on)}$		ı	0.18	ı	
Rise Time*1	t _r	$I_C = 8A, V_{CC} = 300V,$ $V_{GE} = 5V, R_G = 100\Omega,$	ı	0.21	ı	μs
Turn - off Delay Time*1	$t_{d(off)}$	L=5mH, T_j =150°C	ı	1.7	ı	
Fall Time*1	t _f		ı	3.0	ı	
	E _{AS}	$L = 5\text{mH}, V_{GE} = 5\text{V},$ $V_{CC} = 30\text{V}, R_G = 1\text{k}\Omega,$				
Avalanche Energy (Single Pulse)		T _j = 25°C	300	-	-	mJ
		$T_j = 150^{\circ}C^{*2}$	180	-	-	mJ
Gate Series Resistance	R_{G}		70	100	130	Ω
Gate - Emitter Resistance	R_GE		8	16	24	kΩ

^{*1)} Assurance items according to our measurement definition (Fig.18)

^{*2)} Design assurance items

Fig.1 Typical Output Characteristics

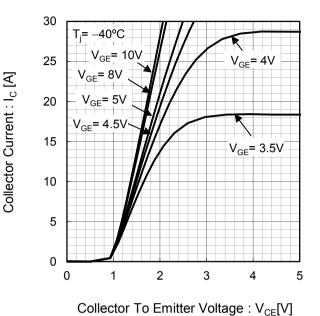
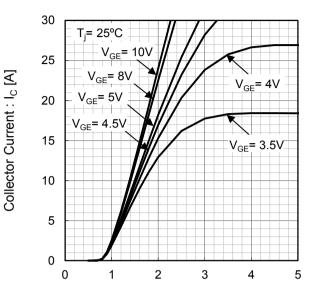


Fig.2 Typical Output Characteristics



Collector To Emitter Voltage : $V_{CE}[V]$

Fig.3 Typical Output Characteristics

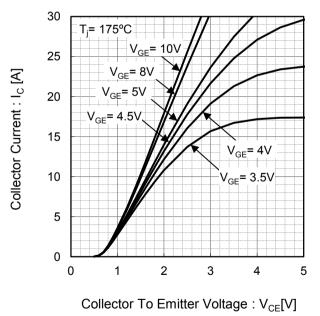
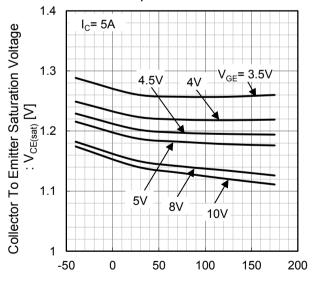


Fig.4 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

Fig.5 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

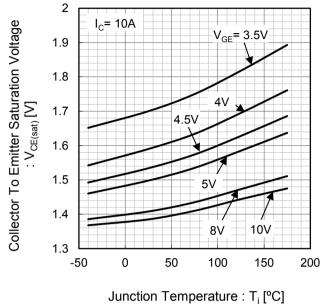
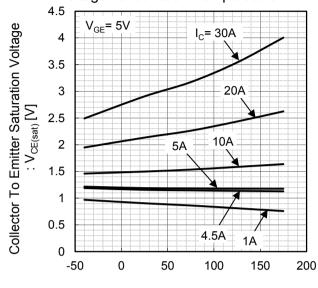


Fig.6 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

Fig.7 Typical Transfer Characteristics

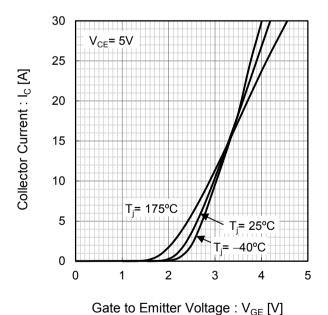
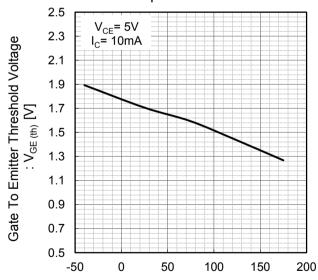
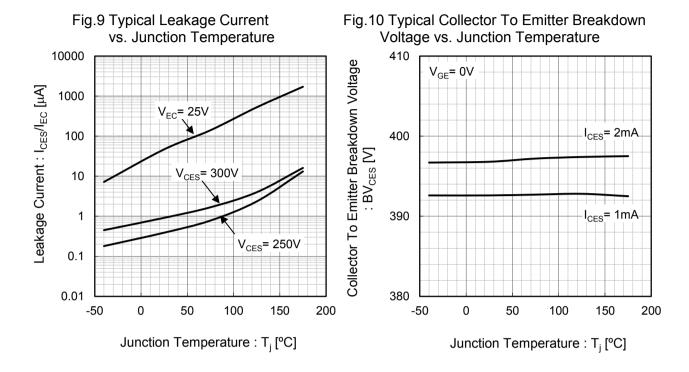


Fig.8 Typical Gate To Emitter Threshold Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]



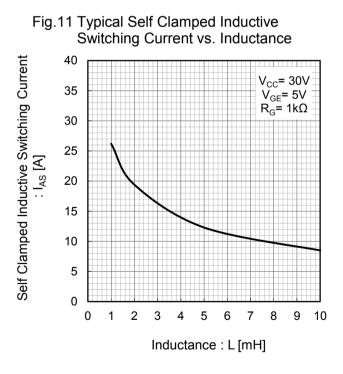


Fig.12 Typical Gate Charge 5 4 3 2 V_{CC}= 12V I_C= 10A 1 $T_i = 25^{\circ}C$ 0 5 20 0 10 15 25 Gate Charge : Qq [nC]

Sate To Emitter Voltage: VGE [V]

Fig.13 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] 100 $\mathsf{C}_{\mathsf{oes}}$ 10 f= 1MHz V_{GE}= 0V C_{res} T_i= 25°C 0.01 0.1 1 10 100

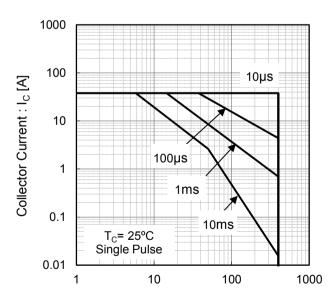
Fig.14 Typical Switching Time vs. Junction Temperature

10 $V_{cc} = 300V, I_{c} = 8A, V_{GE} = 5V, L = 5mH$ $V_{cc} = 5V, L = 5mH$ $V_{doff} = 5V, L = 5mH$

Junction Temperature : T_i [°C]

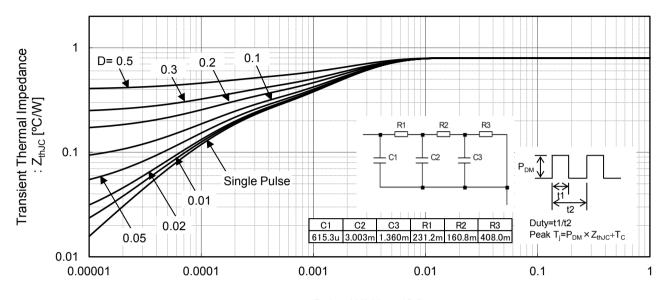
Fig.15 Forward Bias Safe Operating Area

Collector To Emitter Voltage : V_{CE}[V]



Collector To Emitter Voltage : V_{CE}[V]

Fig.16 Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

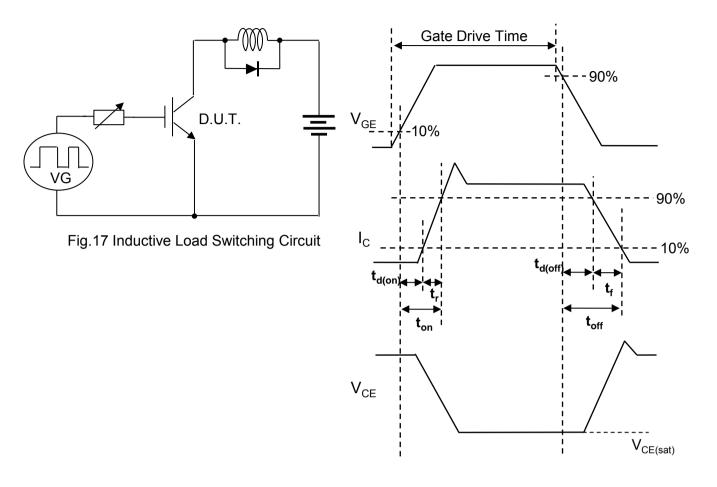


Fig.18 Inductive Load Switching Waveform

● Self Clamped Inductive Switching Circuit and Waveform

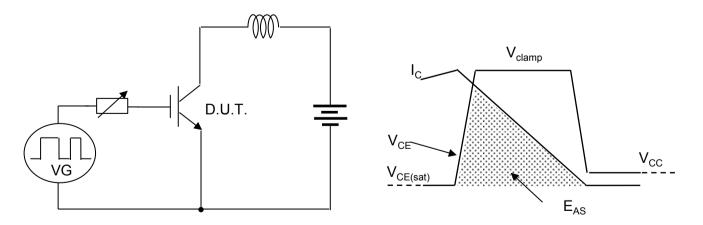


Fig.19 Self Clamped Inductive Switching Ciruit Fig.20 Self Clamped Inductive Switching Waveform

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RGPR30BM40HR - Web Page

Part Number	RGPR30BM40HR
Package	TO-252
Unit Quantity	2500
Minimum Package Quantity	2500
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes